GTM CORPORATION

GDMBD4148

SURFACE MOUNT, SWITCHING DIODE VOLTAGE 75V, CURRENT 0.2A

Description

The GDMBD4148 is designed for high-speed switching application in hybrid thick and thin-film circuits. The devices is manufactured by the silicon epitaxial planar process and packed in plastic surface mount package.

Package Dimensions



Markin	ig :		Circuit:		
D4			∘₋⊢∙⊸		
DEE	Millimeter		DEE	Millimeter	
REF.	Min.	Max.	NEF.	Min.	Max.
Α	0.85	1.05			
A1	0	0.10	L	0.20	0.40
A2	0.80	1.00	b	0.25	0.40
D	1.15	1.45	С	0.10	0.18
E	1.60	1.80			
HE	2.30	2.70	Q1	0.15	BSC.

Absolute Maximum Ratings at Ta = 25℃

Parameter	Symbol	Ratings	Unit
Junction Temperature	Tj	+150	°C
Storage Temperature	Tstg	-65 ~ +150	°C
Maximum Peak Reverse Voltage	V _{RM}	100	V
Maximum Reverse Voltage	V _R	75	V
Average Forward Current	I _O	200	mA
Surge Current(1us)	I _{FSM}	2	А
Typical Junction Capacitance between Terminal (Note 1)	CJ	4.0	pF
Maximum Reverse Recovery Time (Note2)	T _{RR}	4.0	nSec
Total Power Dissipation	PD	225	mW

Electrical Characteristics at Ta = 25°C

Characteristic	Symbol	Min.	Max.	Unit	Test Conditions
Forward Voltage	VF	-	1	V	IF=10mA
Reverse Breakdown	VR	100	-	V	IR=100uA
Reverse Current	IR	-	5	uA	VR=75V

Notes: 1. Measured at 1.0 MHz and applied reverse voltage of 0 volt.

2. Measured at applied forward current of 10mA, reverse current of 1.0mA, Reverse voltage of 6.0volt and RL=100 ohms.

3. ESD sensitive product handling required.

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Characteristics Curve



FIG. 5 - REVERSE RECOVERY TIME MEASUREMENT CIRCUIT



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